

DATA SHEET

NEC

MOS FIELD EFFECT TRANSISTOR μ PA2755AGR

SWITCHING N-CHANNEL POWER MOS FET

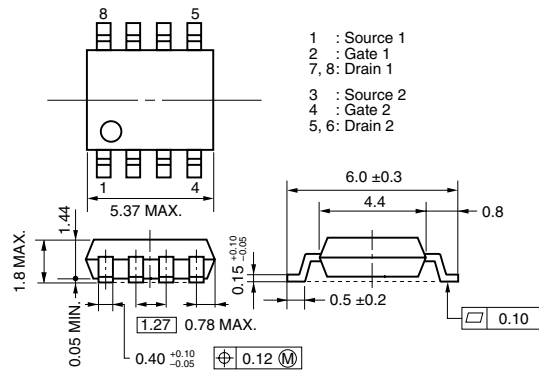
DESCRIPTION

The μ PA2755AGR is Dual N-channel MOS Field Effect Transistor designed for DC/DC converters and power management applications of notebook computers.

FEATURES

- Dual chip type
- Low on-state resistance
 $R_{DS(on)1} = 18 \text{ m}\Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 4.0 \text{ A)}$
 $R_{DS(on)2} = 29 \text{ m}\Omega \text{ MAX. (} V_{GS} = 4.5 \text{ V, } I_D = 4.0 \text{ A)}$
- Low input capacitance
 $C_{iss} = 650 \text{ pF TYP.}$
- Built-in G-S protection diode
- Small and surface mount package (Power SOP8)

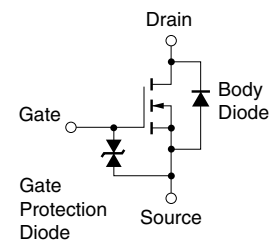
PACKAGE DRAWING (Unit: mm)



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$, All terminals are connected.)

| | | | |
|--|----------------|------------------------|------------------|
| Drain to Source Voltage ($V_{GS} = 0 \text{ V}$) | V_{DSS} | 30 | V |
| Gate to Source Voltage ($V_{DS} = 0 \text{ V}$) | V_{GSS} | ± 20 | V |
| Drain Current (DC) ($T_C = 25^\circ\text{C}$) | $I_{D(DC)}$ | ± 8.0 | A |
| Drain Current (pulse) ^{Note1} | $I_{D(pulse)}$ | ± 32 | A |
| Total Power Dissipation (1 unit) ^{Note2} | P_T | 1.7 | W |
| Total Power Dissipation (2 units) ^{Note2} | P_T | 2.0 | W |
| Channel Temperature | T_{ch} | 150 | $^\circ\text{C}$ |
| Storage Temperature | T_{stg} | $-55 \text{ to } +150$ | $^\circ\text{C}$ |
| Single Avalanche Current ^{Note3} | I_{AS} | 8 | A |
| Single Avalanche Energy ^{Note3} | E_{AS} | 6.4 | mJ |

EQUIVALENT CIRCUIT (1/2 circuit)



- Notes**
1. $PW \leq 10 \mu\text{s}$, Duty Cycle $\leq 1\%$
 2. Mounted on ceramic substrate of $2000 \text{ mm}^2 \times 2.2 \text{ mm}$
 3. Starting $T_{ch} = 25^\circ\text{C}$, $V_{DD} = 15 \text{ V}$, $R_G = 25 \Omega$, $V_{GS} = 20 \rightarrow 0 \text{ V}$

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD.
 When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

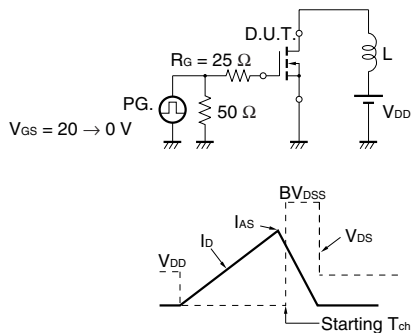
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ELECTRICAL CHARACTERISTICS (TA = 25°C, All terminals are connected.)

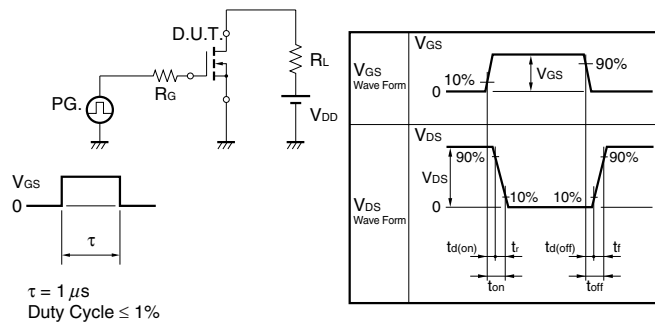
| CHARACTERISTICS | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---|---------------|---|------|------|------|------|
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 30\text{ V}, V_{GS} = 0\text{ V}$ | | | 10 | μA |
| Gate Leakage Current | I_{GSS} | $V_{GS} = \pm 18\text{ V}, V_{DS} = 0\text{ V}$ | | | ±10 | μA |
| Gate to Source Cut-off Voltage | $V_{GS(off)}$ | $V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$ | 1.5 | | 2.5 | V |
| Forward Transfer Admittance Note | $ y_{fs} $ | $V_{DS} = 10\text{ V}, I_D = 4.0\text{ A}$ | 2.8 | 5.7 | | S |
| Drain to Source On-state Resistance Note | $R_{DS(on)1}$ | $V_{GS} = 10\text{ V}, I_D = 4.0\text{ A}$ | | 14 | 18 | mΩ |
| | $R_{DS(on)2}$ | $V_{GS} = 4.5\text{ V}, I_D = 4.0\text{ A}$ | | 21 | 29 | mΩ |
| Input Capacitance | C_{iss} | $V_{DS} = 10\text{ V}$ | | 650 | | pF |
| Output Capacitance | C_{oss} | $V_{GS} = 0\text{ V}$ | | 150 | | pF |
| Reverse Transfer Capacitance | C_{rss} | $f = 1\text{ MHz}$ | | 98 | | pF |
| Turn-on Delay Time | $t_{d(on)}$ | $V_{DD} = 15\text{ V}, I_D = 4.0\text{ A}$ | | 12 | | ns |
| Rise Time | t_r | $V_{GS} = 10\text{ V}$ | | 16 | | ns |
| Turn-off Delay Time | $t_{d(off)}$ | $R_G = 10\text{ }\Omega$ | | 38 | | ns |
| Fall Time | t_f | | | 8.0 | | ns |
| Total Gate Charge | Q_G | $V_{DD} = 24\text{ V}$ | | 13 | | nC |
| Gate to Source Charge | Q_{GS} | $V_{GS} = 10\text{ V}$ | | 2.2 | | nC |
| Gate to Drain Charge | Q_{GD} | $I_D = 8.0\text{ A}$ | | 3.8 | | nC |
| Body Diode Forward Voltage Note | $V_{F(S-D)}$ | $I_F = 8.0\text{ A}, V_{GS} = 0\text{ V}$ | | 0.84 | | V |
| Reverse Recovery Time | t_{rr} | $I_F = 8.0\text{ A}, V_{GS} = 0\text{ V}$ | | 17 | | ns |
| Reverse Recovery Charge | Q_{rr} | $di/dt = 100\text{ A}/\mu\text{s}$ | | 8.2 | | nC |

Note Pulsed

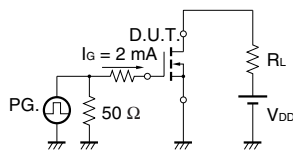
TEST CIRCUIT 1 AVALANCHE CAPABILITY



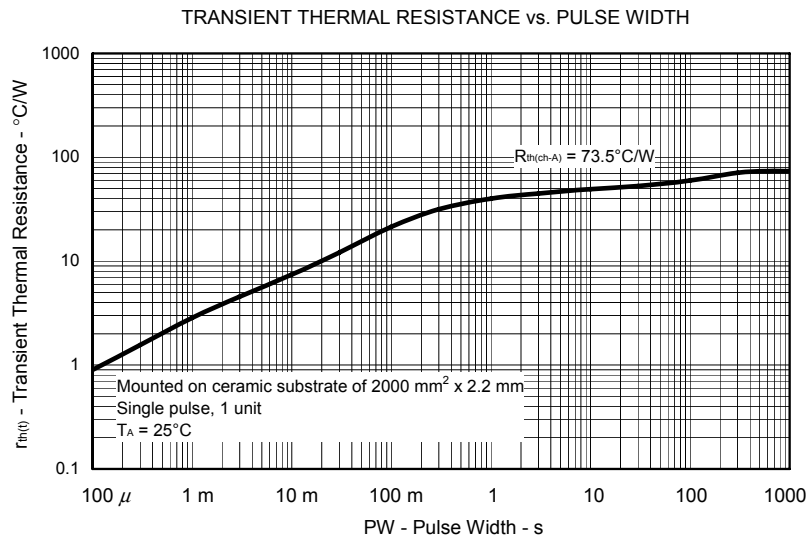
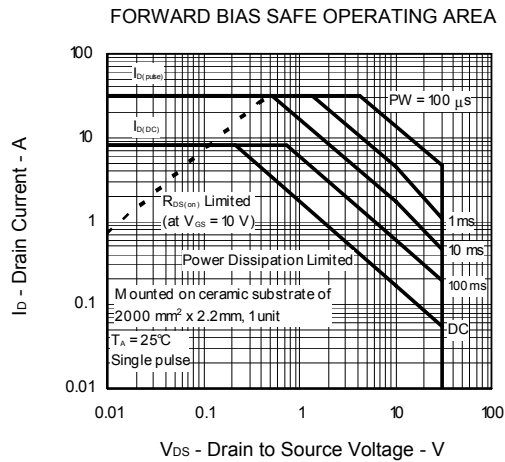
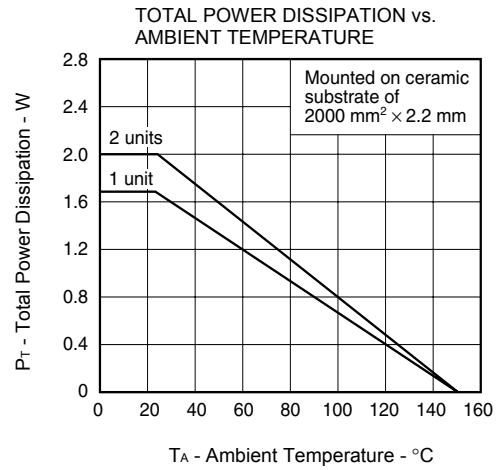
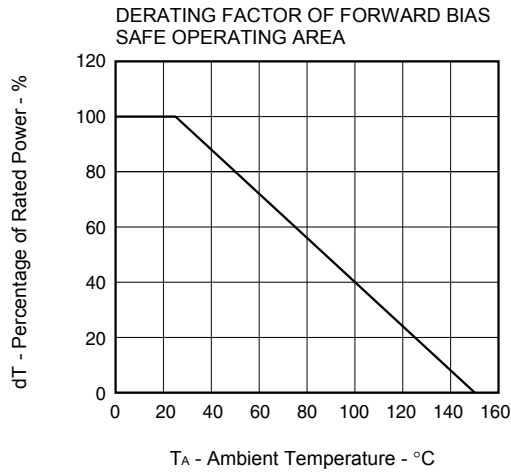
TEST CIRCUIT 2 SWITCHING TIME



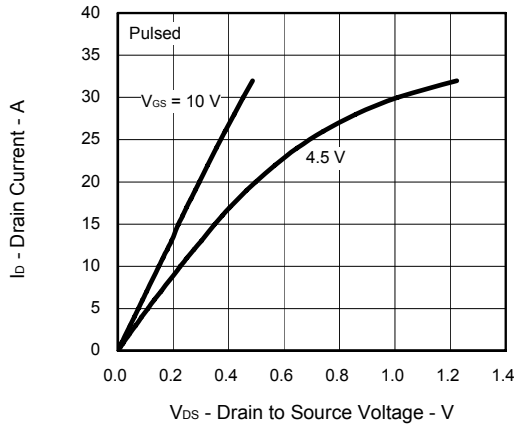
TEST CIRCUIT 3 GATE CHARGE



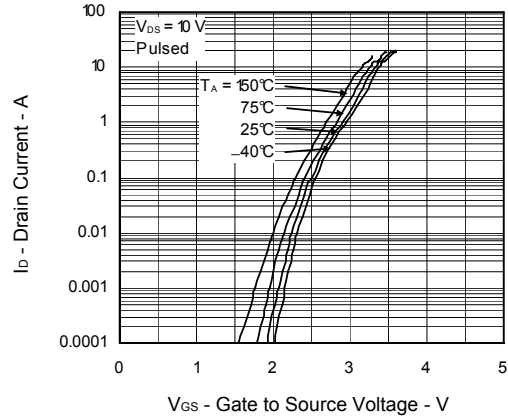
TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)



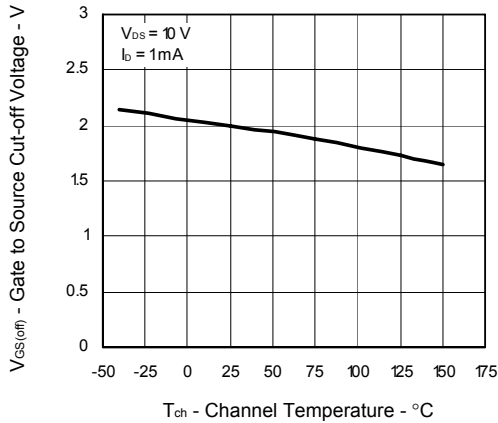
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



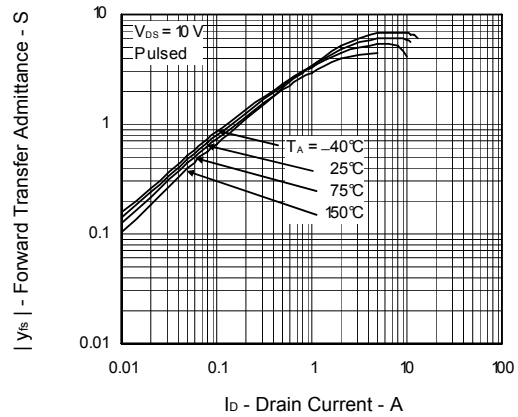
FORWARD TRANSFER CHARACTERISTICS



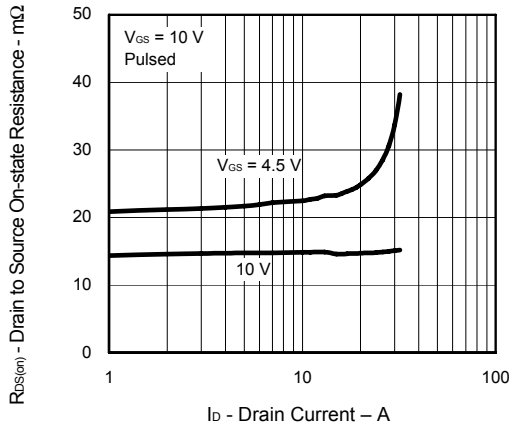
GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



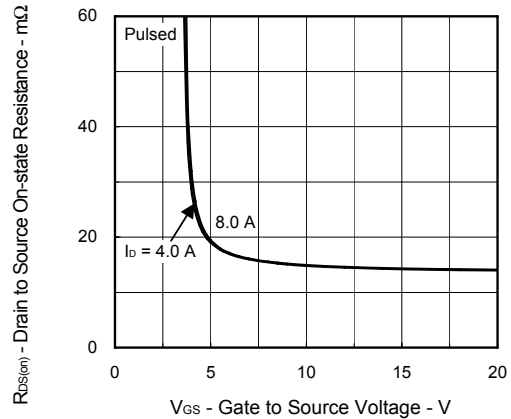
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



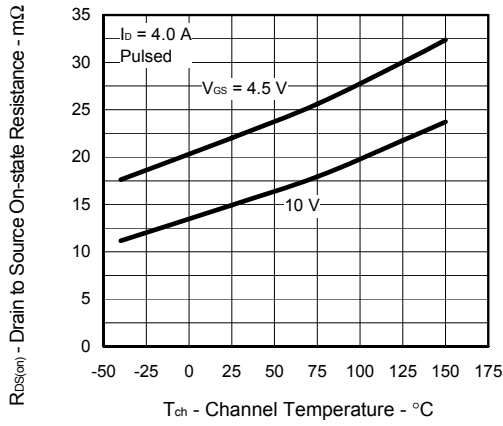
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



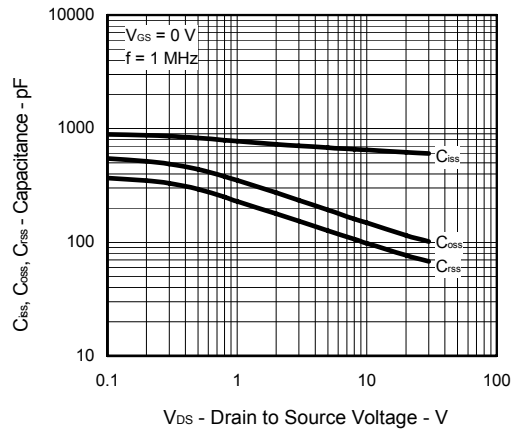
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



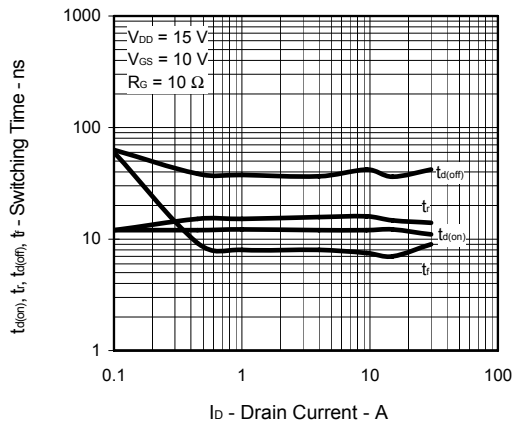
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



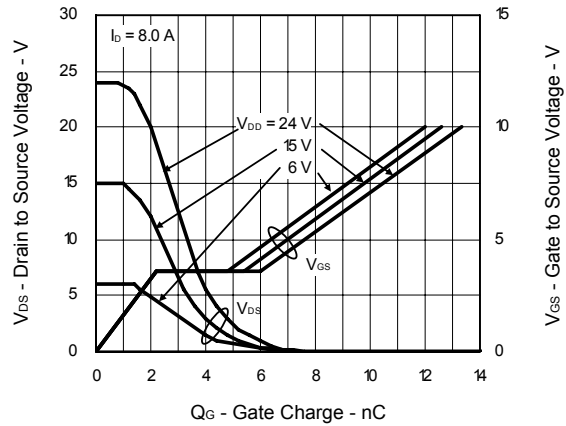
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



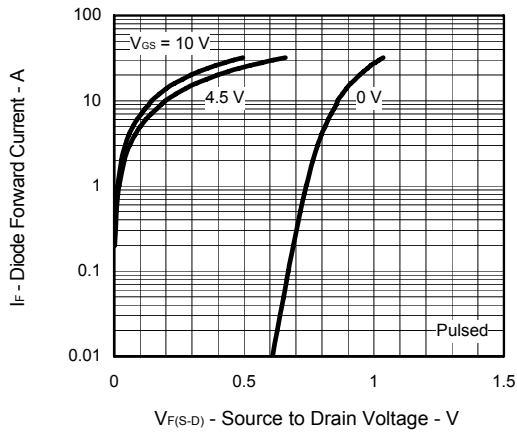
SWITCHING CHARACTERISTICS



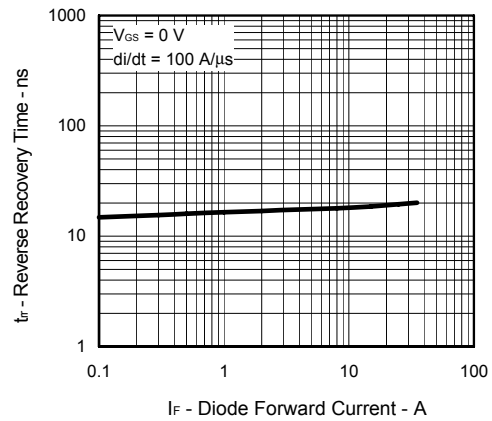
DYNAMIC INPUT/OUTPUT CHARACTERISTICS

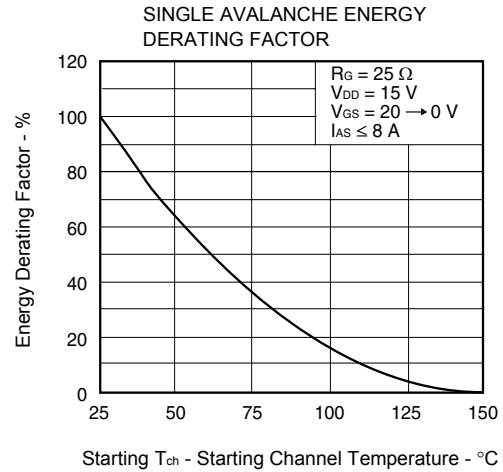
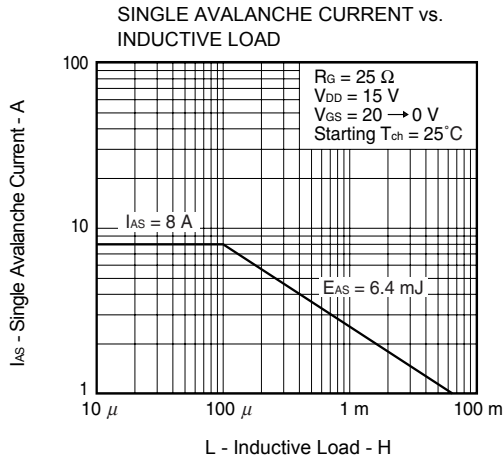


SOURCE TO DRAIN DIODE FORWARD VOLTAGE



REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT





ORDERING INFORMATION

| PART NUMBER | LEAD PLATING | PACKING | PACKAGE |
|---|---------------|------------------|-------------|
| μ PA2755AGR-E1-AT <small>Note</small> | Pure Sn (Tin) | Tape 2500 p/reel | Power SOP8 |
| μ PA2755AGR-E2-AT <small>Note</small> | | | 0.08 g TYP. |

Note Pb-free (This product does not contain Pb in external electrode and other parts.)

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